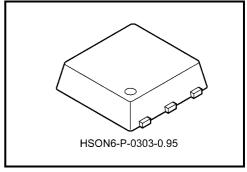
TOSHIBA Bipolar Digital Integrated Circuit Silicon Monolithic

TD62S351AFM

1-Channel Darlington Source-Current Driver

The TD62S351AFM is a 1-channel inverting source-current driver with PNP transistor at the first stage and a NPN Darlington transistor at the second stage.

The driver incorporates an input resistor which limits output pull-down resistance and base current. Because the driver operates by source input current, it is optimal for interfacing with sink-current driven general-purpose CMOS logic ICs and microprocessors. Also, the driver is optimal for driving fluorescent display tubes and LEDs. When using the driver, pay attention to the thermal conditions.



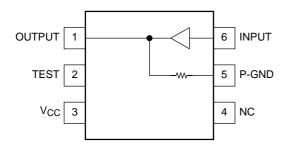
Weight: 0.017 g (typ.)

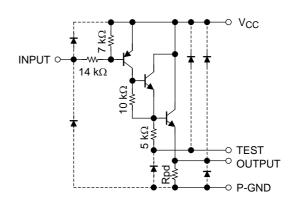
Features

- Ultra-small HSON6 package with heat sink on rear
- Large output voltage: VOUT = -50 V (min)
- Large output current: $I_{OUT} = -500 \text{ mA (max)}$
- Built-in input resistor: $R_{IN} = 14 \text{ k}\Omega$
- Input signal: Low Level Active

Pin Connection (top view)

Basic Circuit Diagram





- Note 1: Diodes shown using dotted lines are parasitic. Do not use them.
- Note 2: When using the driver, connect the OUTPUT pin to the TEST pin.
- Note 3: When using the driver, connect the P-GND pin to the heat sink on the rear of the package.

Maximum Ratings (Ta = 25°C, $V_{CC} = 0 V$)

| Characteristics | Symbol | Rating | Unit | |
|------------------------------|-----------------------------------|----------------|------|--|
| Supply voltage | V _{CC} -V _{GND} | 50 | V | |
| Output voltage | V _{OUT} | -50 | ٧ | |
| Collector-emitter voltage | V _{CEO} | 50 | V | |
| Output current | I _{OUT} | -500 | mA | |
| Input voltage | V _{IN} | -30~0.5 | V | |
| Power dissipation | P _D (Note 4) | 0.78 | W | |
| Saturated thermal resistance | R _{th (j-a)} (Note 4) | 160 | °C/W | |
| Saturated thermal resistance | R _{th (j-c)} (Note 5) | 25 | | |
| Operating temperature | T _{opr} | -40~85 | °C | |
| Storage temperature | T _{stg} | −55~150 | °C | |

Note 4: $114.3 \times 76.2 \times 1.6$ mm glass epoxy film substrate Cu heat dissipation pattern 100 mm²

Note 5: When an infinite heat sink is mounted.

Recommended Operating Condition (Ta = -40~85°C, V_{CC} = 0 V)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------|------------------|-----------------------------------|-----|------|------|------|
| Supply voltage | V _{CC} | _ | 0 | _ | 50 | V |
| Output voltage | V _{OUT} | _ | 0 | _ | -50 | V |
| Output current | I _{OUT} | Ta = 60°C, T _j = 105°C | _ | _ | -130 | mA |
| Input voltage | V _{IN} | _ | -30 | _ | 0 | V |

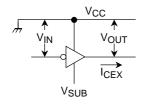
Electrical Characteristics (Ta = 25°C, $V_{CC} = 0 V$)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit | |
|--------------------------------|-----------------------|-----------------|---|------|------|-------|------|--|
| Output leakage current | I _{CEX} | 1 | OUT = PGND = -50 V | _ | _ | -10 | μΑ | |
| Output saturation voltage | V _{CE} (sat) | 2 | PGND = -50 V, V _{IN} = -2.8 V, I _{OUT} = -350 mA | | -1.8 | -2.0 | V | |
| | | | $PGND = -50 \text{ V}, V_{IN} = -2.8 \text{ V}, I_{OUT} = -130 \text{ mA}$ | | -1.5 | -1.75 | | |
| DC current amplification ratio | h _{FE} | 2 | 2 V _{CE} = 3 V, I _{OUT} = -350 mA | | _ | _ | | |
| Input voltage | V _{IN (OFF)} | 4 | $I_{OUT} = -500 \mu A$ | -1.2 | _ | 0 | V | |
| | V _{IN (ON)} | 4 | $V_{CE} = 2 \text{ V}, I_{OUT} = -350 \text{ mA}$ | -30 | _ | -2.8 | | |
| Input current | I _{IN (ON)} | 3 | $V_{CC} - GND = 5.5 V,$ $V_{IN} = GND + 0.4 V$ | _ | _ | -0.45 | mA | |
| Power dissipation | I _{CC} (ON) | 3 | OUT = OPEN, V _{IN} = V _{CC} - 5 V, V _{CC} - GND = 50 V | _ | _ | -0.8 | mA | |
| Output pulldown resistor | Rpd | _ | _ | 168 | 240 | 312 | kΩ | |
| Turn-on delay | t _{ON} | 5 | $V_{OUT} = -50 \text{ V}, R_L = 125 \Omega,$ | _ | 0.1 | _ | 0 | |
| Turn-off delay | tOFF |) J | C _L = 15 pF | _ | 7.0 | _ | μS | |

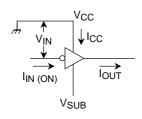
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Test Circuit

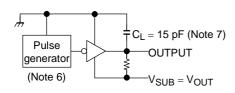
1. I_{CEX}



3. I_{IN} (ON), I_{CC}



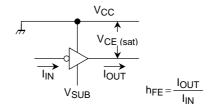
5. ton, toff



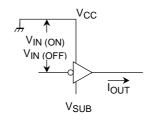
Note 6: Pulse width 50 μ s, Duty cycle 10% Output impedance 50 Ω , $t_f \le 5$ ns, $t_f \le 10$ ns

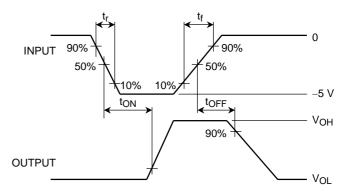
Note 7: C_L includes probe and jig capacitance.

2. $V_{CE (sat)}$, h_{FE}



4. VIN (ON), VIN (OFF)





Caution on Application

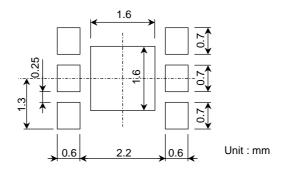
- 1. The device does not include protectors such as an overcurrent protector and an overvoltage protector. Applying excessive current or voltage may damage the device.
 - Thus, design with great care to prevent excessive current or voltage from being applied to the device. The device may also be damaged by short-circuits between outputs and power supply/ground. Take care when designing output, $V_{\rm CC}$ and GND line.
- 2. If the TD62S351AFM is used to drive an inductive load (such as a motor, solenoid, or relay), Toshiba recommends that the diodes be connected between pin 1 and pin 5 so as to absorb the counter electromotive force generated by the load.
 - Please adhere to the maximum ratings of this device.
- 3. Be sure to mount the device in the correct orientation. Make sure that the positive and negative power supply pins are connected the right way round. Otherwise, the absolute maximum current and power dissipation ratings may be exceeded and the device may break down or undergo performance degradation, causing it to catch fire or explode, and resulting in injury.

Package Dimensions

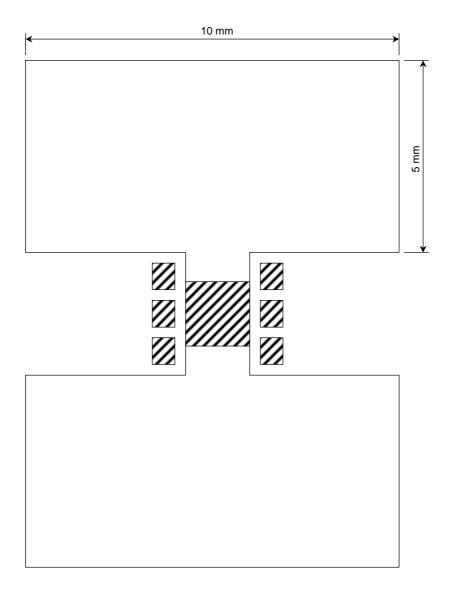
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Weight: 0.017 g (typ.)

Preliminary land pattern



Preliminary PCB trace dimension



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RESTRICTIONS ON PRODUCT USE

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